



查询"SDR2410CTM"供应商
SOLID STATE DEVICES, INC.

14830 Valley View Blvd * La Mirada, Ca 90638
Phone: (562) 404-7855 * Fax: (562) 404-1773

Designer's Data Sheet

FEATURES:

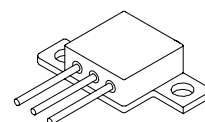
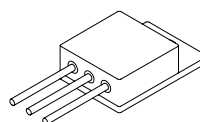
- Ultra Fast Recovery: 65 nsec Maximum
- High Surge Rating
- Low Reverse Leakage Current
- Low Junction Capacitance
- Hermetically Sealed Package
- Ultrasonic Aluminum Wire Bonds
- Ceramic Seal for Improved Hermeticity Available
- Common Anode and Doubler Versions Available
- TX, TXV and Space Level Screening Available

SDR2410CTM
SDR2412CTM

24AMPS
1200 VOLTS
65 nsec
ULTRAFAST
CENTERTAP RECTIFIER

TO-254 (M)

TO-254Z (Z)



Maximum Ratings	SYMBOL	VALUE	UNITS
Peak Repetitive Reverse and DC Blocking Voltage SDR2410CTM SDR2412CTM	V_{RRM} V_{RWM} V_R	1000 1200	Volts
Average Rectified Forward Current. (Resistive load, 60Hz, Sine Wave, $T_A = 25^\circ\text{C}$) <u>1/</u>	I_O	24	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, $T_C = 55^\circ\text{C}$, $I_O = 12\text{A}$) <u>2/</u>	I_{FSM}	75	Amps
Operating and Storage Temperature	$T_{OP} \& T_{stg}$	-65 TO +200	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case, <u>1/</u> Junction to Case, <u>2/</u>	$R_{\theta JC}$	1.2 2.4	$^\circ\text{C/W}$

NOTE:

- 1/ Both Legs Tied Together
2/ Per Leg.

NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RC0068A

SDR2410CTM

SDR2412CTM

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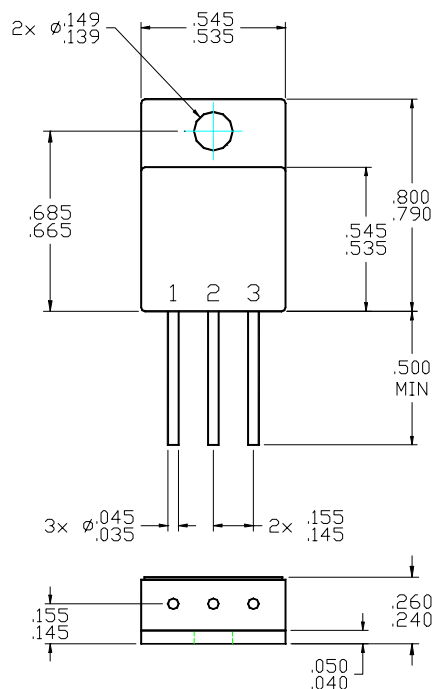
Electrical Characteristics (Per Leg)	SYMBOL	MINIMUM	MAXIMUM	UNITS
Instantaneous Forward Voltage Drop ($T_A = 25^\circ\text{C}$, 300 μsec Pulse) $I_F = 12\text{A}$	V_{F1}	—	1.9	V_{DC}
Instantaneous Forward Voltage Drop $T_A = 100^\circ\text{C}$ ($I_F = 12\text{A}$, 300 μsec pulse) $T_A = -55^\circ\text{C}$	V_{F2} V_{F3}	—	1.8 2.2	V_{DC}
Reverse Leakage Current $T_A = 25^\circ\text{C}$ (80% of Rated V_R , 300 μs pulse min.) $T_C = 100^\circ\text{C}$	I_{R1} I_{R2}	— —	50 2.5	μA mA
Junction Capacitance ($V_R = 10V_{DC}$, $T_A = 25^\circ\text{C}$, $f = 1\text{MHz}$)	C_J	—	60	pF
Reverse Recovery Time ($I_F = 500\text{mA}$, $I_R = 1.0\text{A}$, $I_{RR} = 250\text{mA}$, $T_A = 25^\circ\text{C}$)	t_{RR}	—	65	nsec

CASE OUTLINE: TO-254 (Sufix M)

PIN 1: ANODE 1

PIN 2: CATHODE

PIN 3: ANODE 2



CASE OUTLINE: TO-254Z (Sufix Z)

PIN 1: ANODE 1

PIN 2: CATHODE

PIN 3: ANODE 2

